# Quad Analog Switch/ Quad Multiplexer

The MC14016B quad bilateral switch is constructed with MOS P-channel and N-channel enhancement mode devices in a single monolithic structure. Each MC14016B consists of four independent switches capable of controlling either digital or analog signals. The quad bilateral switch is used in signal gating, chopper, modulator, demodulator and CMOS logic implementation.

#### **Features**

- Diode Protection on All Inputs
- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- Linearized Transfer Characteristics
- Low Noise  $12 \text{ nV/}\sqrt{\text{Cycle}}$ ,  $f \ge 1.0 \text{ kHz typical}$
- Pin-for-Pin Replacements for CD4016B, CD4066B (Note improved transfer characteristic design causes more parasitic coupling capacitance than CD4016)
- For Lower R<sub>ON</sub>, Use The HC4016 High–Speed CMOS Device or The MC14066B
- This Device Has Inputs and Outputs Which Do Not Have ESD Protection. Antistatic Precautions Must Be Taken.

• Pb-Free Packages are Available

MAXIMUM RATINES (/) t/g > Feference d to V ss)

Symbol	Parameter	Value	unit
$V_{DD}$	DC Supply Voltage Range	-0.5 to +18.0	V
V <sub>in</sub> , V <sub>out</sub>	Input or Output Voltage Range (DC or Transient)	-0.5 to V <sub>DD</sub> + 0.5	<b>V</b>
l <sub>in</sub>	Input Current (DC or Transient) per Control Pin	±10	mA
I <sub>SW</sub>	Switch Through Current	±25	mA
P <sub>D</sub>	Power Dissipation, per Package (Note 1)	500	mW
T <sub>A</sub>	Ambient Temperature Range	-55 to +125	°C
T <sub>stg</sub>	Storage Temperature Range	-65 to +150	°C
TL	Lead Temperature (8–Second Soldering)	260	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Temperature Derating:

Plastic "P and D/DW" Packages: - 7.0 mW/°C From 65°C To 125°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation,  $V_{in}$  and  $V_{out}$  should be constrained to the range  $V_{SS} \leq (V_{in} \text{ or } V_{out}) \leq V_{DD}.$ 

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either  $V_{SS}$  or  $V_{DD}$ ). Unused outputs must be left open.



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MARKING DIAGRAMS



PDIP-14 P SUFFIX CASE 646



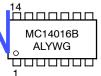


SOIC-14 D SUFFIX CASE 751A





SOLIAJ-14 F SUFFID CAST 965



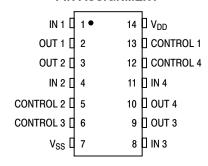
A = Assembly Location

WL, L = Wafer Lot
YY, Y = Year
WW, W = Work Week
G = Pb-Free Indicator

#### **ORDERING INFORMATION**

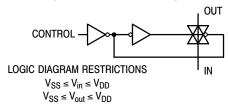
See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

#### **PIN ASSIGNMENT**

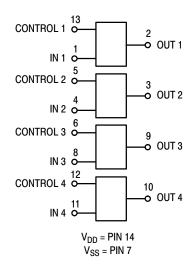


#### **LOGIC DIAGRAM**

(1/4 OF DEVICE SHOWN)



#### **BLOCK DIAGRAM**



Control	Switch
0 = V <sub>SS</sub>	Off
1 = V <sub>DD</sub>	On

ORDERING INFORMATION	I)	m / ( )N	
Device	Раскаде	enipping <sup>†</sup>	
MC14016BCP	PDIP-14		
MC14016BCPG	PDIP-14 (Pb-Free)	25 / Tape & Ammo Box	
MC14016BD	SOIC-14		
MC14016BDG	SOIC-14 (Pb-Free)	55 Units / Rail	
MC14016BDR2	SOIC-14		
MC14016BDR2G	SOIC-14 (Pb-Free)	2500 / Tape & Reel	
MC14016BFEL	SOEIAJ-14		
MC14016BFELG	SOEIAJ-14 (Pb-Free)	2000 / Tape & Reel	

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

### **ELECTRICAL CHARACTERISTICS** (Voltages Referenced to V<sub>SS</sub>)

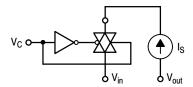
			V <sub>DD</sub>	- 5	5°C	25°C		125°C			
Characteristic	Figure	Symbol	Vdc	Min	Max	Min	Typ <sup>(2)</sup>	Max	Min	Max	Unit
Input Voltage Control Input	1	V <sub>IL</sub>	5.0 10 15	- - -	- - -	- - -	1.5 1.5 1.5	0.9 0.9 0.9	- - -	- - -	Vdc
		V <sub>IH</sub>	5.0 10 15	- - -	- - -	3.0 8.0 13	2.0 6.0 11	- - -	- - -	- - -	Vdc
Input Current Control	-	l <sub>in</sub>	15	-	±0.1	-	±0.00001	±0.1	-	± 1.0	μAdc
Input Capacitance Control Switch Input Switch Output Feed Through	-	C <sub>in</sub>	- - - -	- - - -	- - - -	- - - -	5.0 5.0 5.0 0.2	- - - -	- - - -	- - - -	pF
Quiescent Current (Per Package) <sup>(3)</sup>	2,3	I <sub>DD</sub>	5.0 10 15	- - -	0.25 0.5 1.0	- - -	0.0005 0.0010 0.0015	0.25 0.5 1.0	- - -	7.5 15 30	μAdc
"ON" Resistance $(V_C = V_{DD}, R_L = 10 \text{ k}\Omega)$ $(V_{in} = +5.0 \text{ Vdc})$ $(V_{in} = -5.0 \text{ Vdc}) \text{ V}_{SS} = -5.0 \text{ Vdc}$ $(V_{in} = \pm 0.25 \text{ Vdc})$ $(V_{in} = +7.5 \text{ Vdc})$ $(V_{in} = -7.5 \text{ Vdc}) \text{ V}_{SS} = -7.5 \text{ Vdc}$ $(V_{in} = \pm 0.25 \text{ Vdc})$ $(V_{in} = \pm 0.25 \text{ Vdc})$ $(V_{in} = +10 \text{ Vdc})$ $(V_{in} = +0.25 \text{ Vdc}) \text{ V}_{SS} = 0 \text{ Vdc}$	4,5,6	R <sub>ON</sub>	5.0 7.5		600 600 600 360 360 360 600	- - - - - -	300 300 280 240 240 180 260 310	660 660 400 400 400 660	- - - - - -	840 840 840 520 520 520 840 840	Ohms
$(V_{in} = +5.6 \text{ Vdo})$ $(V_{in} = +15 \text{ Vdc})$ $(V_{in} = +0.25 \text{ Vdc})$ $(V_{in} = +9.3 \text{ Vdc})$	B	DT	1 15	<u>-</u>	360 360 360	CC	260 300	60 200 400 400	<u>-</u>	520 520 520 520	
$\Delta$ "ON" Resistance Between any 2 circuits in a common package $ \begin{array}{l} (\text{V}_{\text{C}} = \text{V}_{\text{DD}}) \\ (\text{V}_{\text{in}} = \pm 5.0 \text{ Vdc}, \text{V}_{\text{SS}} = -5.0 \text{ Vdc}) \\ (\text{V}_{\text{in}} = \pm 7.5 \text{ Vdc}, \text{V}_{\text{SS}} = -7.5 \text{ Vdc}) \end{array} $	_	ΔR <sub>ON</sub>	5.0 7.5	-	_ _		15 10	-		_ _ _	Ohms
Input/Output Leakage Current ( $V_C = V_{SS}$ ) ( $V_{in} = +7.5$ , $V_{out} = -7.5$ Vdc) ( $V_{in} = -7.5$ , $V_{out} = +7.5$ Vdc)	-	-	7.5 7.5	- -	±0.1 ±0.1	- -	±0.0015 ±0.0015	±0.1 ±0.1	- -	± 1.0 ± 1.0	μAdc

<sup>NOTE: All unused inputs must be returned to V<sub>DD</sub> or V<sub>SS</sub> as appropriate for the circuit application.
2. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.
3. For voltage drops across the switch (ΔV<sub>switch</sub>) > 600 mV ( > 300 mV at high temperature), excessive V<sub>DD</sub> current may be drawn; i.e., the current out of the switch may contain both V<sub>DD</sub> and switch input components. The reliability of the device will be unaffected unless the Maximum Ratings are exceeded. (See first page of this data sheet.) Reference Figure 14.</sup> 

# **ELECTRICAL CHARACTERISTICS** (4) $(C_L = 50 \text{ pF}, T_A = 25^{\circ}\text{C})$

Characteristic	Figure	Symbol	V <sub>DD</sub> Vdc	Min	Typ <sup>(5)</sup>	Max	Unit
Propagation Delay Time ( $V_{SS}$ = 0 Vdc) $V_{in}$ to $V_{out}$ ( $V_C$ = $V_{DD}$ , $R_L$ = 10 k $\Omega$ )	7	t <sub>PLH</sub> , t <sub>PHL</sub>	5.0 10 15	- - -	15 7.0 6.0	45 15 12	ns
Control to Output $(V_{in} \le 10 \text{ Vdc}, R_L = 10 \text{ k}\Omega)$	8	t <sub>PHZ</sub> , t <sub>PLZ</sub> , t <sub>PZH</sub> , t <sub>PZL</sub>	5.0 10 15	- - -	34 20 15	90 45 35	ns
Crosstalk, Control to Output ( $V_{SS}$ = 0 Vdc) ( $V_{C}$ = $V_{DD}$ , $R_{in}$ = 10 k $\Omega$ , $R_{out}$ = 10 k $\Omega$ , f = 1.0 kHz)	9	-	5.0 10 15	- - -	30 50 100	- - -	mV
Crosstalk between any two switches ( $V_{SS} = 0 \text{ Vdc}$ ) $(R_L = 1.0 \text{ k}\Omega, f = 1.0 \text{ MHz},$ $\text{crosstalk} = 20 \log_{10} \frac{V_{out1}}{V_{out2}}$	-	-	5.0	-	- 80	-	dB
Noise Voltage ( $V_{SS} = 0 \text{ Vdc}$ ) ( $V_C = V_{DD}$ , $f = 100 \text{ Hz}$ ) ( $V_C = V_{DD}$ , $f = 100 \text{ kHz}$ )	10,11	-	5.0 10 15 5.0 10	- - - -	24 25 30 12 12	- - - -	nV/√Cycle
Second Harmonic Distortion ( $V_{SS} = -5.0 \text{ Vdc}$ ) ( $V_{in} = 1.77 \text{ Vdc}$ , RMS Centered @ 0.0 Vdc, R <sub>L</sub> = 10 k $\Omega$ , f = 1.0 kHz)	-	-	15 5.0	-	15 0.16	-	%
Insertion Loss ( $V_C = V_{DD}$ , $V_{in} = 1.77$ Vdc, $V_{SS} = -5.0$ Vdc, RMS centered = 0.0 Vdc, f = 1.0 MHz) $I_{loss} = 20 log 0 V_{OUt} V_{IN} V_{IN}$	12	<b>S</b> .	5.0	) M	23 02 0.1 0.05	N	dB
Bandwidth (– 3.0 dB) $ (V_C = V_{DD},  V_{in} = 1.77  \text{Vdc},  V_{SS} = -5.0  \text{Vdc}, \\ \text{RMS centered @ 0.0 Vdc)} \\ (R_L = 1.0  \text{k}\Omega) \\ (R_L = 10  \text{k}\Omega) \\ (R_L = 100  \text{k}\Omega) \\ (R_L = 1.0  \text{M}\Omega) $	12,13	BW	5.0	- - - -	54 40 38 37	- - -	MHz
$\label{eq:off-control} \begin{array}{l} \text{OFF Channel Feedthrough Attenuation} \\ (V_{SS} = -5.0 \text{ Vdc}) \\ (V_{C} = V_{SS}, 20 \log_{10} \ \frac{V_{out}}{V_{in}} = -50  \text{dB}) \\ (R_{L} = 1.0  \text{k}\Omega) \\ (R_{L} = 10  \text{k}\Omega) \\ (R_{L} = 100  \text{k}\Omega) \\ (R_{L} = 1.0  \text{M}\Omega) \end{array}$	-	-	5.0	- - - -	1250 140 18 2.0	- - -	kHz

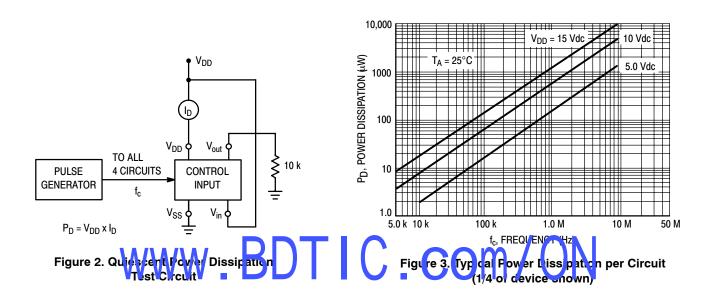
<sup>4.</sup> The formulas given are for typical characteristics only at 25°C.
5. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.



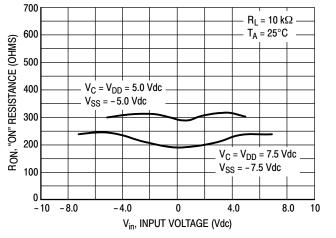
 $\begin{array}{l} V_{IL} \colon V_{C} \text{ is raised from } V_{SS} \text{ until } V_{C} = V_{IL}. \\ \text{at } V_{C} = V_{IL} \colon I_{S} = \pm 10 \ \mu\text{A with } V_{in} = V_{SS}, \ V_{out} = V_{DD} \text{ or } V_{in} = V_{DD}, \ V_{out} = V_{SS}. \end{array}$ 

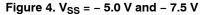
 $V_{IH}$ : When  $V_C$  =  $V_{IH}$  to  $V_{DD}$ , the switch is ON and the  $R_{ON}$  specifications are met.

Figure 1. Input Voltage Test Circuit



## TYPICAL R<sub>ON</sub> versus INPUT VOLTAGE





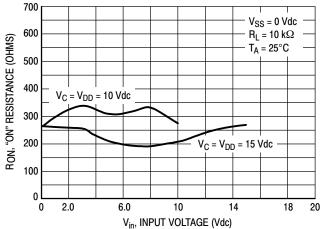


Figure 5.  $V_{SS} = 0 V$ 

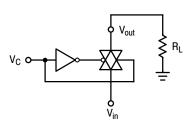


Figure 6. R<sub>ON</sub> Characteristics Test Circuit

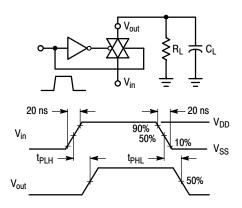


Figure 7. Propagation Delay Test Circuit and Waveforms

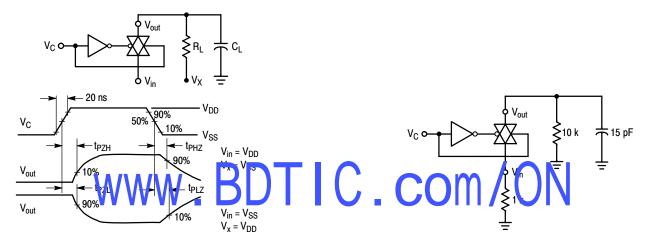


Figure 8. Turn-On Delay Time Test Circuit and Waveforms

Figure 9. Crosstalk Test Circuit

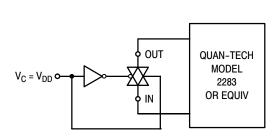


Figure 10. Noise Voltage Test Circuit

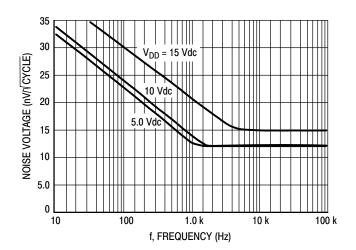


Figure 11. Typical Noise Characteristics

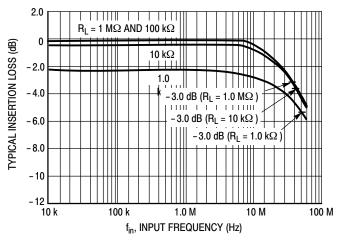


Figure 12. Typical Insertion Loss/Bandwidth Characteristics

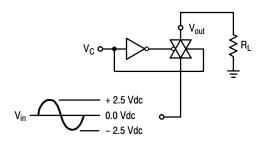


Figure 13. Frequency Response Test Circuit

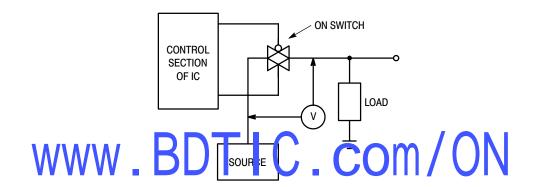


Figure 14.  $\Delta V$  Across Switch

#### **APPLICATIONS INFORMATION**

Figure A illustrates use of the Analog Switch. The 0-to-5 V Digital Control signal is used to directly control a 5  $\rm V_{p-p}$  analog signal.

The digital control logic levels are determined by  $V_{DD}$  and  $V_{SS}$ . The  $V_{DD}$  voltage is the logic high voltage; the  $V_{SS}$  voltage is logic low. For the example,  $V_{DD}$  = +5 V logic high at the control inputs;  $V_{SS}$  = GND = 0 V logic low.

The maximum analog signal level is determined by  $V_{DD}$  and  $V_{SS}$ . The analog voltage must not swing higher than  $V_{DD}$  or lower than  $V_{SS}$ .

The example shows a 5  $V_{p-p}$  signal which allows no margin at either peak. If voltage transients above  $V_{DD}$  and/or below  $V_{SS}$  are anticipated on the analog channels, external diodes  $(D_x)$  are recommended as shown in Figure B. These diodes should be small signal types able to absorb the maximum anticipated current surges during clipping.

The *absolute* maximum potential difference between  $V_{DD}$  and  $V_{SS}$  is 18.0 V. Most parameters are specified up to 15 V which is the *recommended* maximum difference between  $V_{DD}$  and  $V_{SS}$ .

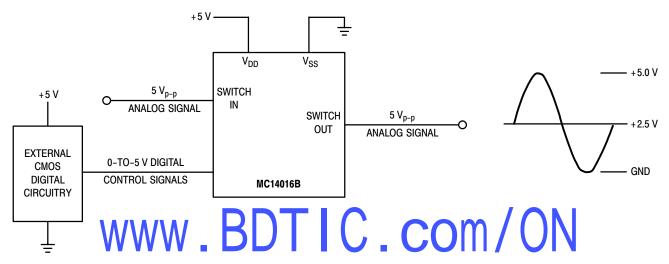


Figure A. Application Example

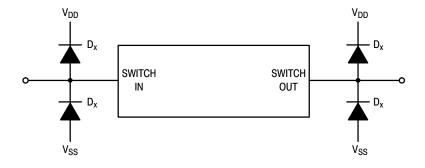
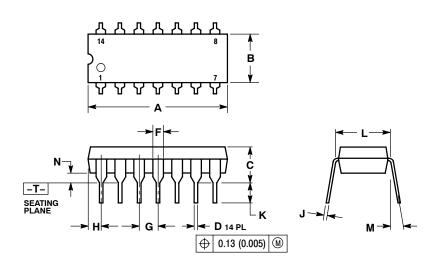


Figure B. External Germanium or Schottky Clipping Diodes

#### **PACKAGE DIMENSIONS**

PDIP-14 CASE 646-06 **ISSUE P** 



- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- Y14.5M, 1982.

  2. CONTROLLING DIMENSION: INCH.

  3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.

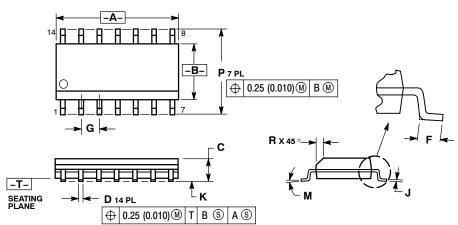
  4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
- 5. ROUNDED CORNERS OPTIONAL.

	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.715	0.770	18.16	19.56
В	0.240	0.260	6.10	6.60
С	0.145	0.185	3.69	4.69
D	0.015	0.021	0.38	0.53
F	0.040	0.070	1.02	1.78
G	0.100	BSC	2.54	BSC
Н	0.052	0.095	1.32	2.41
7	0.008	0.015	0.20	0.38
K	0.115	0.135	2.92	3.43
L	0.290	0.310	7.37	7.87
M		10 °		10 °
N	0.015	0.039	0.38	1.01

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#### PACKAGE DIMENSIONS

SOIC-14 CASE 751A-03 **ISSUE H** 



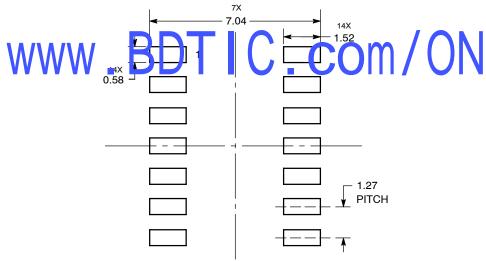
- NOTES:
  1. DIMENSIONING AND TOLERANCING PER
- ANSI Y14.5M, 1982.

  2. CONTROLLING DIMENSION: MILLIMETER.

  3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
- 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
- 5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIN	IETERS	INCHES		
DIM	MIN	MIN MAX		MAX	
Α	8.55	8.75	0.337	0.344	
В	3.80	4.00	0.150	0.157	
С	1.35	1.75	0.054	0.068	
D	0.35	0.49	0.014	0.019	
F	0.40	1.25	0.016	0.049	
G	1.27	BSC	0.050	BSC	
J	0.19	0.25	0.008	0.009	
K	0.10	0.25	0.004	0.009	
М	0 °	7 °	0 °	7 °	
Р	5.80	6.20	0.228	0.244	
R	0.25	0.50	0.010	0.019	

#### **SOLDERING FOOTPRINT\***

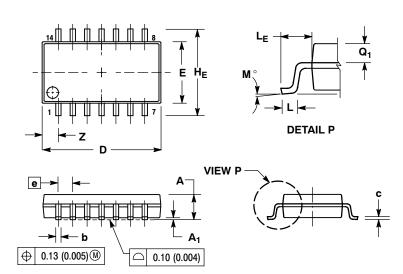


DIMENSIONS: MILLIMETERS

<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### PACKAGE DIMENSIONS

SOEIAJ-14 CASE 965-01 **ISSUE A** 



- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: MILLIMETER.
   DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) PER SIDE
- 4. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
- THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 ( 0.018).

	MILLIN	METERS	INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α		2.05	2.05 0		
A <sub>1</sub>	0.05	0.20	0.002	0.008	
b	0.35	0.50	0.014	0.020	
C	0.10	0.20	0.004	0.008	
D	9.90	10.50	0.390	0.413	
E	5.10	5.45	0.201	0.215	
е	1.27	BSC	0.050 BSC		
HE	7.40	8.20	0.291	0.323	
0.50	0.50	0.85	0.020	0.033	
LE	1.10	1.50	0.043	0.059	
M	_ 0°	10 °	_0 °	10°	
$Q_1$	0. J	0.	028	0.035	
Z		1 2		0.056	

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